ROHS
Available on commercial versions

## Schottky Barrier Diode MELF Surface Mount

Qualified per MIL-PRF-19500/444
DESCRIPTION
This Schottky barrier diode is metallurgically bonded and offers military grade qualifications for high-reliability applications. This small diode is hermetically sealed and bonded into a DO-213AA glass package. Also included in this datasheet are Microsemi's CDLL numbered variants of this series (military qualification grades not are not available for the CDLL prefix part numbers).

Important: For the latest information, visit our website http://www.microsemi.com.

## FEATURES

- Surface mount equivalent of JEDEC registered 1N5711, 1N5712, 1N6857, and 1N6858 numbers.
- Hermetically sealed glass construction.
- Metallurgically bonded.
- Double plug construction.
- JAN, JANTX, JANTXV and commercial qualifications also available per MIL-PRF-19500/444 on "1N" numbers only.
(See Part Nomenclature for all available options).
- RoHS compliant versions available (commercial grade only).


## APPLICATIONS / BENEFITS

- Low reverse leakage characteristics.
- Small size for high density mounting using the surface mount method (see package illustration).
- ESD sensitive to Class 1.

MAXIMUM RATINGS @ $25{ }^{\circ} \mathrm{C}$ unless otherwise stated

| Parameters/Test Conditions | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Junction and Storage Temperature | $\mathrm{T}_{\text {J }}$ and $\mathrm{T}_{\text {STG }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance, Junction-to-End Cap | $\mathrm{R}_{\text {өJEC }}$ | 250 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Average Rectified Output Current: $\begin{array}{r} 5711 \& 6263 \text { types }{ }^{(1)} \\ 2810,5712 \& 6858 \text { types }{ }^{(2)} \\ 6857 \text { types }{ }^{(3)} \end{array}$ | Io | $\begin{gathered} 33 \\ 75 \\ 150 \end{gathered}$ | mA |
| Solder Temperature @ 10 s |  | 260 | ${ }^{\circ} \mathrm{C}$ |

NOTES: 1. At $\mathrm{T}_{\mathrm{EC}}$ and $\mathrm{T}_{\mathrm{SP}}=+140^{\circ} \mathrm{C}$, derate $\mathrm{I}_{\mathrm{O}}$ to 0 at $+150^{\circ} \mathrm{C}$.
2. At $T_{E C}$ and $T_{S P}=+130^{\circ} \mathrm{C}$, derate $I_{O}$ to 0 at $+150^{\circ} \mathrm{C}$.
3. At $T_{E C}$ and $T_{S P}=+110^{\circ} \mathrm{C}$, derate $I_{O}$ to 0 at $+150^{\circ} \mathrm{C}$.

Qualified Levels: JAN, JANTX, and JANTXV


## DO-213AA (MELF)

 PackageAlso available in:

UB package
(3-pin surface mount)
1N5711UB, 1N5712UB
(B, CC, CA)

## DO-35 package

(axial-leaded)
1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1

MSC - Lawrence
6 Lake Street, Lawrence, MA 01841
Tel: 1-800-446-1158 or
(978) 620-2600

Fax: (978) 689-0803
MSC - Ireland
Gort Road Business Park, Ennis, Co. Clare, Ireland
Tel: +353 (0) 656840044
Fax: +353 (0) 656822298
Website:
www.microsemi.com

## MECHANICAL and PACKAGING

- CASE: Hermetically sealed glass DO-213AA MELF (SOD-80, LL34) case package.
- TERMINALS: Tin/lead plated or RoHS compliant matte-tin (on commercial grade only) over copper clad steel. Solderable per MIL-STD-750, method 2026.
- POLARITY: Cathode end is banded.
- MOUNTING: The axial coefficient of expansion (COE) of this device is approximately $+6 \mathrm{PPM} /{ }^{\circ} \mathrm{C}$. The COE of the mounting surface system should be selected to provide a suitable match with this device.
- MARKING: Part number.
- TAPE \& REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: Approximately 0.2 grams.
- See Package Dimensions on last page.


## PART NOMENCLATURE



| SYMBOLS \& DEFINITIONS |  |
| :---: | :--- |
| Symbol | Definition |
| C | Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage. |
| f | frequency |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage $\mathrm{V}_{\mathrm{R}}$. |
| $\mathrm{I}_{\mathrm{O}}$ | Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave <br> input and a 180 degree conduction angle. |
| $\mathrm{t}_{\mathrm{rr}}$ | Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from <br> the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs. |
| $\mathrm{V}_{(\mathrm{BR})}$ | Breakdown Voltage: A voltage in the breakdown region. |
| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current. |
| $\mathrm{V}_{\mathrm{R}}$ | Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region. |
| $\mathrm{V}_{\mathrm{RWM}}$ | Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes <br> known historically as PIV. |

ELECTRICAL CHARACTERISTICS @ $T_{A}=25^{\circ} \mathrm{C}$ unless otherwise noted

| TYPE NUMBER | $\qquad$ | MAXIMUM FORWARD VOLTAGE | MAXIMUM FORWARD VOLTAGE | WORKING PEAK REVERSE VOLTAGE | MAXIMUM REVERSE LEAKAGE CURRENT |  | MAXIMUM CAPACITANCE <br> @ $\mathrm{V}_{\mathrm{R}}=0$ <br> VOLTS <br> $\mathrm{f}=1.0 \mathrm{MHz}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{V}_{\text {(BR) }} @ 10 \mu \mathrm{~A}$ | $\mathrm{V}_{\mathrm{F}}$ @ 1 mA | $\mathrm{V}_{\mathrm{F}} @ \mathrm{I}_{\mathrm{F}}$ | $\mathrm{V}_{\text {RWM }}$ | $\mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{R}}$ |  | $\mathrm{C}_{\text {T }}$ |
|  | Volts | Volts | V @ mA | V (pk) | nA | Volts | pF |
| 1N5711UR-1 | 70 | 0.41 | 1.0 @ 15 | 50 | 200 | 50 | 2.0 |
| 1N5712UR-1 | 20 | 0.41 | 1.0 @ 35 | 16 | 150 | 16 | 2.0 |
| 1N6857UR-1 | 20 | 0.35 | 0.75 @ 35 | 16 | 150 | 16 | 4.5 |
| 1N6858UR-1 | 70 | 0.36 | 0.65 @ 15 | 50 | 200 | 50 | 4.5 |
| CDLL2810 | 20 | 0.41 | 1.0 @ 35 | 50 | 100 | 15 | 2.0 |
| CDLL5711 | 70 | 0.41 | 1.0 @ 15 | 50 | 200 | 50 | 2.0 |
| CDLL5712 | 20 | 0.41 | 1.0 @ 35 | 16 | 150 | 16 | 2.0 |
| CDLL6263 | 60 | 0.41 | 1.0 @ 15 | 16 | 200 | 50 | 2.2 |
| CDLL6857 | 20 | 0.35 | 0.75 @ 35 | 16 | 150 | 16 | 4.5 |
| CDLL6858 | 70 | 0.36 | 0.65 @ 15 | 50 | 200 | 50 | 4.5 |

## NOTE:

1. Effective minority carrier lifetime $(\tau)$ is 100 pico seconds.

## GRAPHS



FIGURE 1
I-V Curve showing typical Forward Voltage Variation
Temperature for the 1N5712UR-1, CDLL5712 and CDLL2810 Schottky Diodes


FIGURE 2
1N5712UR-1, CDLL5712 and CDLL2810 Typical variation of Reverse Current ( $\mathrm{I}_{\underline{\underline{R}}}$ ) vs Reverse Voltage ( $\mathrm{V}_{\underline{R}}$ ) at Various Temperatures

## GRAPHS



FIGURE 3
I-V curve showing typical Forward Voltage Variation With Temperature Schottky Diode 1N5711UR-1


FIGURE 4
1N5711UR-1 Typical Variation of Reverse Current (I) $\underline{I}_{R}$ vs Reverse Voltage ( $V_{R}$ )
at Various Temperatures

## GRAPHS



FIGURE 5
Typical Dynamic Resistance ( $\mathrm{R}_{\underline{D}}$ ) vs Forward Current ( $\mathrm{I}_{\underline{E}}$ )


| DIM | INCH |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| BD | 0.063 | 0.067 | 1.60 | 1.70 |
| BL | 0.130 | 0.146 | 3.30 | 3.71 |
| ECT | 0.016 | 0.022 | 0.41 | 0.56 |
| S | 0.001 min |  | 0.03 min |  |

## NOTES:

1. Dimensions are in inches. Millimeters are given for information only.
2. Dimensions are pre-solder dip.
3. Referencing to dimension S, minimum clearance of glass body to mounting surface on all orientations.
4. In accordance with ASME Y14.5M, diameters are equivalent to $\Phi$ x symbology.

## PAD LAYOUT



|  | INCH | mm |
| :---: | :---: | :---: |
| A | 0.200 | 5.08 |
| B | 0.055 | 1.40 |
| C | 0.080 | 2.03 |

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Schottky Diodes \& Rectifiers category:
Click to view products by Microchip manufacturer:
Other Similar products are found below :
MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30
BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10130A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TBE SK32A-TP SK33B-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LRHF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081 SB560 PMAD1108-LF

